Features and Benefits

Temp. stability less than +/- 10 ppb -10C to +70C operation CMOS output 3.3V

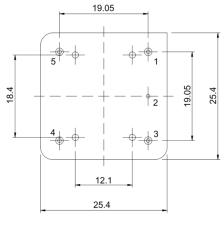
Typical Applications

GPS or Beidou Navigation Systems Test Equipment, and synthesizers Communications Systems

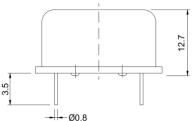
Description

The OCXO2525N ovenized oscillator family is an industry standard configuration offering a small OCXO footprint for high performance applications requiring OCXO type stability and phase noise, but in a smaller profile enclosure.

Mechanical Drawing & Pin Connections



PIN NO.	CONNECTION				
1	RF OUTPUT				
2	GROUND				
3	CONTROL VOLTAGE				
4	NOT CONNECTED				
5	SUPPLY VOLTAGE				



Specification

Oscillator Specification		Sym Condition	Value			Unit	Note	
			Condition	Min.	Тур.	Max.	Unit	Note
Operational Frequency Range		F _{nom}			17.000000		MHz	
LVCMOS	Logic Level 1			+2.4			V	
	Logic Level 0					+0.4	V	
	Rise / Fall Time					10	ns	
	Duty Cycle			45	50	55	%	
Power Suppl	ly							
Voltage		V_{cc}		3.15	3.30	3.45	V	
Current Cons	Current Consumption		Warm-up			4.0	Watts	
Ourient Consumption			Steady-state, +25℃			2.2	Watts	
Warm-up Tim	ne:	T_{up}	To within +/- 50 ppb, at +25°C			300	sec	ref. frequency after 30 min.
Frequency C	ontrol*							
Control voltage	Control voltage range (Pin 3)			0.00	1.65	3.30	V	
Tuning range				+/- 1.0			ppm	
Slope (Linearity)			Positive			+/- 10	%	
Input Impedance when pin 3 OPEN				100K			ohm	
Frequency S	tability							
Versus tempe	erature		-10°C to +70°C, ref 25°C	-10.0		+10.0	ppb	
Tolerance at 25°C			After turn on +5 minutes	-100		+100	ppb	Ref. freq. after 30 min. ON
Versus 5% change in supply voltage				-5.0		+5.0	ppb	
Daily Aging			Per Day maximum after 30 days on	-1.0		+1.0	ppb	
First Year Ag	ing		•	-0.100		+0.100	ppm	
SSB Phase noise (typ.) @ 17 MHz CMOS output and Vcc = 3.3V			100 Hz			-130.0	dBc/Hz	
			1000 Hz			-145.0		
			10 KHz			-150.0		
			100 KHz			-150.0		
Short-Term 100 samples	Tau = 1 second					1.0	E-11	
	100 samples							
	tal Conditions							
	nperature range	-10°C t						
Storage temp	erature range	-55°C t	o +105°C					

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